

## isc N-Channel MOSFET Transistor

# IRFB7730,IIRFB7730

#### • FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on) ≤2.6mΩ
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION





· Battery powered circuits

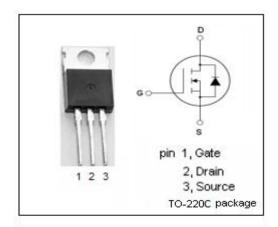


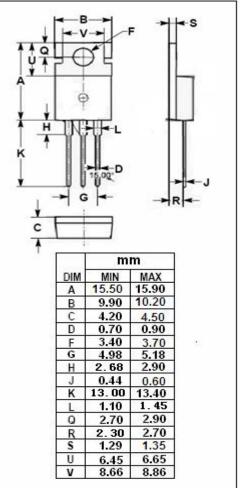
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	VALUE	UNIT			
V <sub>DSS</sub>	Drain-Source Voltage	ource Voltage 75				
V <sub>GS</sub>	Gate-Source Voltage	V				
I <sub>D</sub>	Drain Current-Continuous	Α				
I <sub>DM</sub>	Drain Current-Single Pulsed	984	Α			
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25°C	375	W			
Tj	ax. Operating Junction Temperature 175		$^{\circ}$			
T <sub>stg</sub>	Storage Temperature -55~175		${\mathbb C}$			

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.4	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62	°C/W	







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; ID = 250μA	75			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> ; I <sub>D</sub> =250 μ A	2.1		3.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =100A			2.6	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> =± 20V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =75V; V <sub>GS</sub> = 0V			1	μ <b>А</b>
V <sub>SD</sub>	Diode forward voltage	Is =100A, V <sub>GS</sub> = 0 V			1.2	V

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